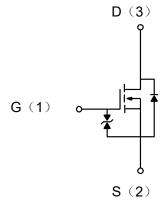


#### Description

PNM723T703E0-2 is designed for high speed switching applications

The enhancement mode MOS is extremely high density cell and low on-resistance.

MOSFET Product Summary					
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	$V_{GS(th)}(V)$	I <sub>D</sub> (A)		
40	7.5@ V <sub>GS</sub> =10V	0.5 to 1.5	0.18		



#### Electrical characteristics per line@25℃ (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	Drain-Source Breakdown Voltage V <sub>DSS</sub> I <sub>D</sub> =250μA,V <sub>GS</sub> =0V		40	-	-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V	-	-	0.5	μA	
Gate-Body Leakage Current	Igss	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	±10	μA	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	0.5	-	1.5	V	
Static Drain-Source On-Resistance	Б	V <sub>GS</sub> =5V, I <sub>D</sub> =0.05A	-	-	7.5	Ω	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =0.5A	-	-	7.5	Ω	
Diode Forward Voltage	Diode Forward Voltage V <sub>SD</sub>		-	0.72	1	V	
Maximum Body-Diode Continuous  Current	Is		-	-	0.2	А	
DYNAMIC PARAMETERS							
Input Capacitance	C <sub>ISS</sub>		-	-	40	pF	
Output Capacitance	C <sub>DSS</sub>	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1MHz	-	-	20	pF	
Reverse Transfer Capacitance	Crss	1- 11VII 12	-	-	5	pF	
Total Gate Charge	Qg		-	0.23	-		
Gate-to-Source Charge	Qgs	$I_D = 0.2A, V_{DS} = 6V,$ $V_{GS} = 4.5V$	-	0.05	-	nC	
Gate-to-Drain(Miller) Charge	Qgd	V 65 - <del>T</del> . O V	-	0.06	-		

Rev.06.9 1 www.prisemi.com

## Electrical characteristics per line@25℃ (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units	
SWITCHING PARAMETERS							
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DS}$ =30V, $V_{GS}$ =10V, $R_G$ =25 $\Omega$ , $R_L$ =150 $\Omega$	-	-	20	ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D = 0.2A$	-	-	20	ns	
Reverse recovery time	trr			11.3		nS	
Reverse recovery charge	Qrr	IF=0.2A, dI/dt=100A/μs		7.5		nC	
Reverse recovery current	Irrm			0.66		Α	

## Absolute maximum rating@25℃

Rating		Symbol	Value	Units
Drain-Source Voltage		V <sub>DS</sub>	40	V
Gate-Source Voltage		V <sub>GS</sub>	±20	V
Dunin Oursent	Continuous	lο	0.18	А
Drain Current	Pulsed	I <sub>D</sub>	0.36	А
Total Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	150	mW
Junction and Storage Temperature Range		TJ, Tstg	-55~+150	$^{\circ}$

#### **Typical Characteristics**

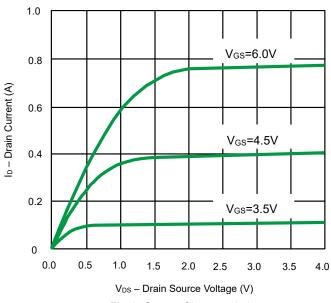


Fig 1. Output Characteristics

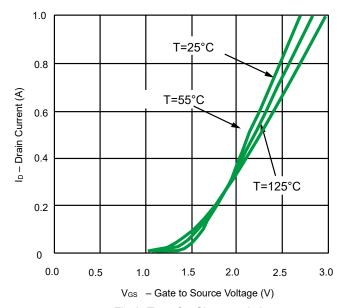


Fig 2. Transfer Characteristics

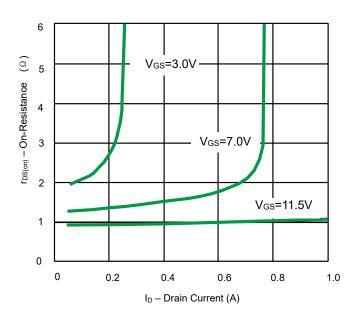


Fig 3. On-Resistance vs. Drain Current

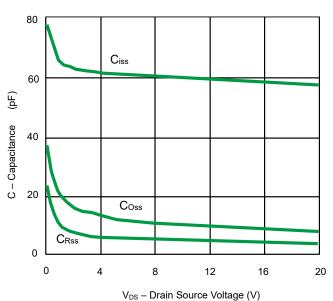
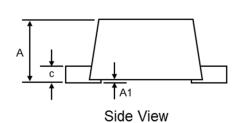
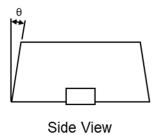
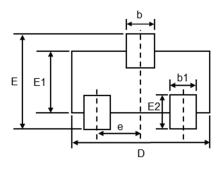


Fig 4. Capacitance

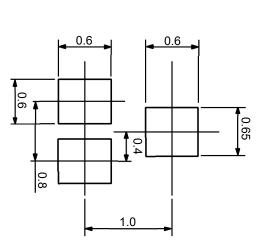
## Product dimension (SOT-723)







**Bottom View** 

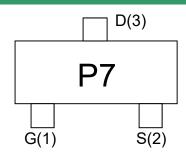


Direc	Millimeters		Inches		
Dim	Min	Max	Min	Max	
Α	0.40	0.55	0.016	0.022	
A1	0.00	0.05	0.000	0.002	
b	0.20	0.37	0.008	0.015	
b1	0.15	0.27	0.006	0.011	
С	0.06	0.18	0.002	0.007	
D	1.10	1.30	0.043	0.051	
Е	1.10	1.30	0.043	0.051	
E1	0.70	0.90	0.028	0.035	
E2	0.20	0.30	0.008	0.012	
е	0.40 Ref.		0.016 Ref.		
θ	5°	9°	5°	9°	

Unit: mm

Suggested PCB Layout

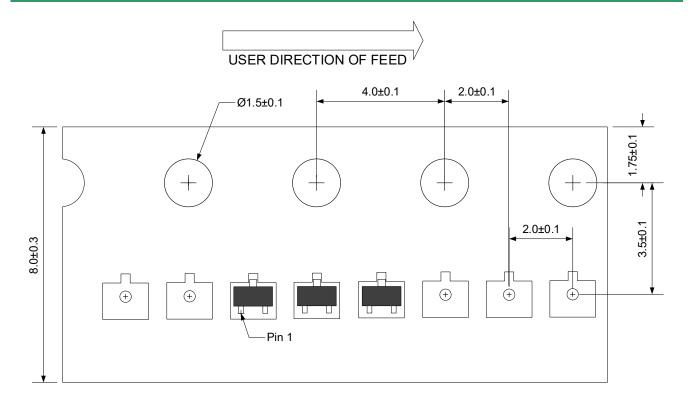
# Marking information



## Ordering information

Device	Package	Reel	Shipping	
PNM723T703E0-2	SOT-723 (Pb-Free)	7"	10000 / Tape & Reel	

## Load with information



Unit:mm

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